

**PLEASE AMEND THE SPECIFICATION AS FOLLOWS:**

After the title, insert -- This is a continuation of Patent Application serial number 10/002,031, filing date 11/30/01, Complementary Metal Oxide Semiconductor Transistor Technology Using Selective Epitaxy Of A Strained Silicon Germanium Layer, assigned to the same assignee as the present invention.

**REMARKS**

A reference to the parent case has been added by Preliminary Amendment to this Continuation Patent Application.

The application is believed to be in condition for allowance. Allowance of the subject Patent Application is therefore respectfully requested.

Respectfully submitted,

A handwritten signature in black ink, appearing to be 'S. Ackerman', written in a cursive style.

STEPHEN B. ACKERMAN, REG. NO. 37,761